Product data sheet

1. Product profile

1.1 General description

Single high-speed switching diode, encapsulated in a SOD323F (SC-90) very small and flat lead Surface-Mounted Device (SMD) plastic package.

1.2 Features

- High switching speed: $t_{rr} \le 50$ ns
- Low leakage current
- Repetitive peak reverse voltage: V_{RRM} ≤ 300 V
- Excellent coplanarity and improved thermal behavior
- Low capacitance: C_d ≤ 2 pF
- Reverse voltage: V_R ≤ 300 V
- Very small and flat lead SMD plastic package

1.3 Applications

- High-speed switching
- General-purpose switching
- Voltage clamping
- Reverse polarity protection

1.4 Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I _F	forward current		<u>[1]</u> -	-	250	mA
I _R	reverse current	$V_{R} = 250 \text{ V}$	-	-	150	nA
V_R	reverse voltage		-	-	300	V
t _{rr}	reverse recovery time		[2] _	-	50	ns

^[1] Pulse test: $t_0 \le 300 \,\mu\text{s}$; $\delta \le 0.02$.



^[2] When switched from I_F = 30 mA to I_R = 30 mA; R_L = 100 Ω ; measured at I_R = 3 mA.

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2. Pinning information

Table 2. Pinning

Pin	Description	Simplified outline	Symbol
1	cathode	[1]	1.4
2	anode	1 2	+
		<u> </u>	sym006

^[1] The marking bar indicates the cathode.

3. Ordering information

Table 3. Ordering information

Type number	Package			
	Name	Description	Version	
BAS21J	SC-90	plastic surface-mounted package; 2 leads	SOD323F	

4. Marking

Table 4. Marking codes

Type number	Marking code
BAS21J	AN

Single high-speed switching diode

5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

		• • •	,		
Symbol	Parameter	Conditions	Min	Max	Unit
V_{RRM}	repetitive peak reverse voltage		-	300	V
V_R	reverse voltage		-	300	V
I _F	forward current		<u>[1]</u> _	250	mA
I _{FRM}	repetitive peak forward current	$t_p \leq 0.5 \text{ ms}; \\ \delta \leq 0.25$	-	1	Α
I _{FSM}	non-repetitive peak forward current	square wave	[2]		
		$t_p = 100 \; \mu s$	-	3	Α
		$t_p = 1 \text{ ms}$	-	2.3	Α
		$t_p = 10 \text{ ms}$	-	1.7	А
P _{tot}	total power dissipation	$T_{amb} \le 25 ^{\circ}C$	[3][4]	550	mW
Tj	junction temperature		-	150	°C
T _{amb}	ambient temperature		-65	+150	°C
T _{stg}	storage temperature		-65	+150	°C

^[1] Pulse test: $t_p \le 300 \ \mu s$; $\delta \le 0.02$.

6. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1][2]	-	230	K/W
$R_{th(j-sp)}$	thermal resistance from junction to solder point		[3] _	-	55	K/W

^[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for cathode 1 cm².

^[2] $T_i = 25$ °C prior to surge.

^[3] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for cathode 1 cm²

^[4] Reflow soldering is the only recommended soldering method.

^[2] Reflow soldering is the only recommended soldering method.

^[3] Soldering point of cathode tab.

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7. Characteristics

Table 7. Characteristics

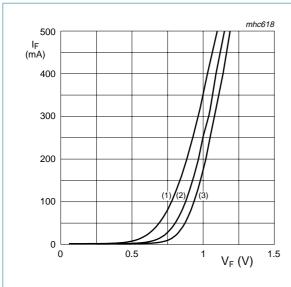
 $T_{amb} = 25 \,^{\circ}C$ unless otherwise specified.

	•					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{F}	forward voltage	$I_F = 100 \text{ mA}$	<u>[1]</u> _	-	1.1	V
I _R	reverse current	V _R = 250 V	-	-	150	nA
		$V_R = 250 \text{ V}; T_j = 150 ^{\circ}\text{C}$	-	-	50	μΑ
C_d	diode capacitance	$V_R = 0 V$; $f = 1 MHz$	-	-	2	pF
t _{rr}	reverse recovery time		[2] _	-	50	ns

^[1] Pulse test: $t_p \le 300~\mu s;~\delta \le 0.02.$

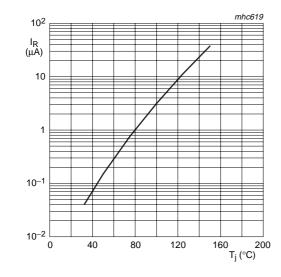
^[2] When switched from I_F = 30 mA to I_R = 30 mA; R_L = 100 Ω ; measured at I_R = 3 mA.

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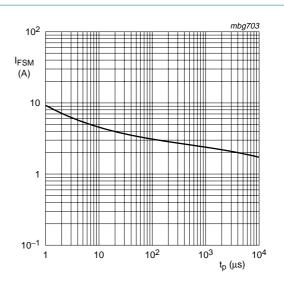
- (1) $T_{amb} = 150 \, ^{\circ}C$
- (2) $T_{amb} = 75 \,^{\circ}C$
- (3) $T_{amb} = 25 \, ^{\circ}C$

Fig 1. Forward current as a function of forward voltage; typical values



 $V_{R} = 250 \text{ V}$

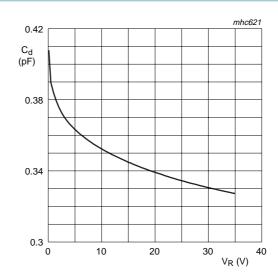
Fig 3. Reverse current as a function of junction temperature; typical values



Based on square wave currents.

 $T_i = 25$ °C; prior to surge

Fig 2. Non-repetitive peak forward current as a function of pulse duration; maximum values



 $f = 1 \text{ MHz}; T_{amb} = 25 \, ^{\circ}\text{C}$

Fig 4. Diode capacitance as a function of reverse voltage; typical values

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8. Test information

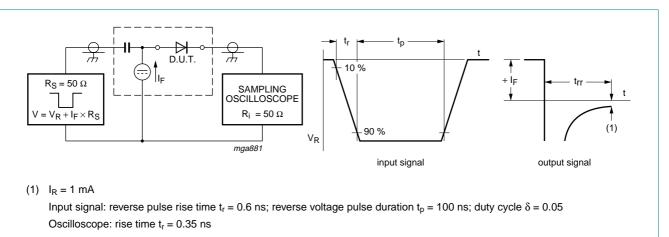
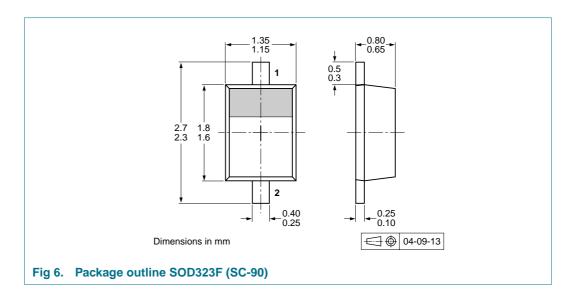


Fig 5. Reverse recovery time test circuit and waveforms

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9. Package outline



10. Packing information

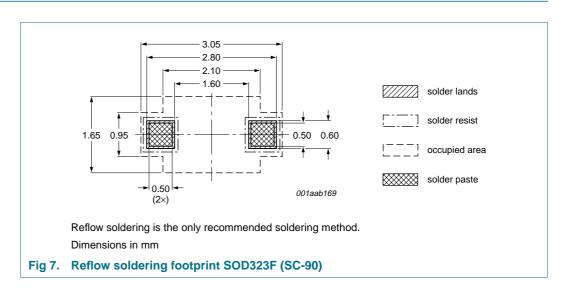
Table 8. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

Type number	Package	Description	Packing qu	antity
			3000	10000
BAS21J	SOD323F	4 mm pitch, 8 mm tape and reel	-115	-135

^[1] For further information and the availability of packing methods, see Section 14.

11. Soldering



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12. Revision history

Table 9. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BAS21J_1	20070308	Product data sheet	-	-

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13. Legal information

13.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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